ΡΛΝ	ĴΪΤ
	SEMI CONDUCTOR

30V N-Channel Enhancement Mode MOSFET

Voltage

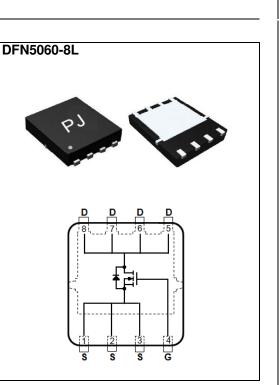
30 V Current

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@16A < 9m\Omega$ $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@8A < 13m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

60A

PARAMET	ER	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	-	60		
	T _C =100°C	I _D	38	A	
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	240		
Power Dissipation	T _C =25°C	PD	54		
	T _C =100°C		21.6		
Continuous Drain Current	T _A =25°C	I _D	10.5		
	T _A =70°C		8.4	A	
Power Dissipation	T _A =25°C	D	2.0		
Power Dissipation	T _A =70°C	Po	1.3	W	
Single Pulse Avalanche Energ	y ^(Note 2)	E _{AS}	45	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{\theta JC}$	2.3	°0.00	
	Junction to Ambient	$R_{\theta JA}$	62.5	°C/W	

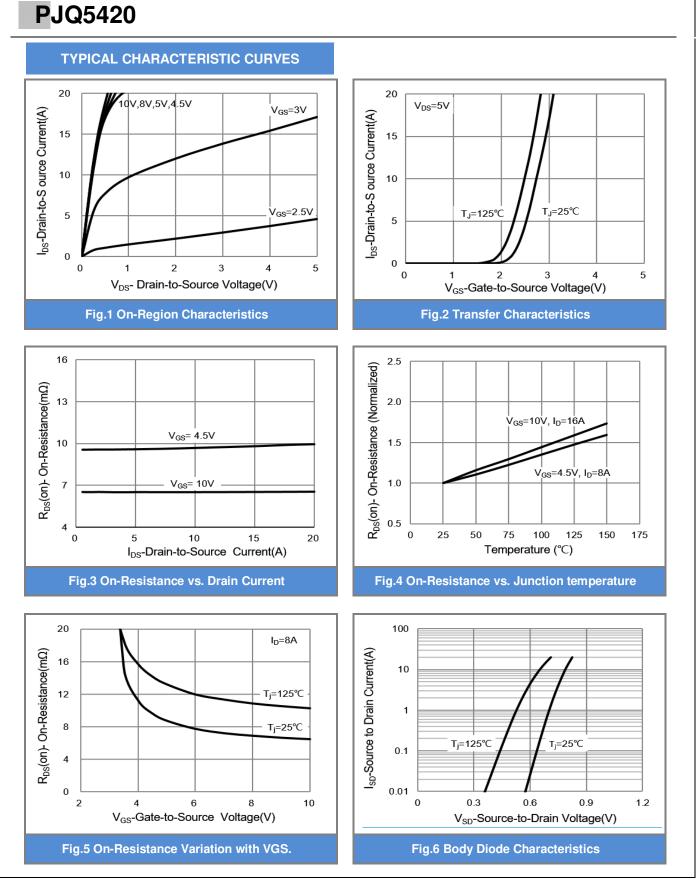


Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V,I _D =250uA	30	-	-	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250uA	1	1.62	2.5	V
Drain-Source On-State Resistance		V _{GS} =10V,I _D =16A	-	6.2	9	mΩ
	$R_{DS(on)}$	V _{GS} =4.5V,I _D =8A	-	9.6	13	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)		•				
Total Gate Charge	Qg	V_{DS} =15V, I _D =20A, V_{GS} =-4.5V ^(Note 2,3)	-	7.1	-	nC
Gate-Source Charge	Q _{gs}		-	3.1	-	
Gate-Drain Charge	Q _{gd}		-	2.0	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	763	-	pF
Output Capacitance	Coss		-	132	-	
Reverse Transfer Capacitance	Crss		-	81	-	
Turn-On Delay Time	td _(on)	V _{DS} =15V,I _D =15A, V _{GS} =10V, R _G =3.3Ω (Note 2,3)	-	6.3	-	
Turn-On Rise Time	tr		-	81	-	ns
Turn-Off Delay Time	td _(off)		-	18	-	
Turn-Off Fall Time	t _f		-	95	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					60	А
Diode Forward Current	l _S		-	-	60	
Diode Forward Voltage	V_{SD}	I _S =1A,V _{GS} =0V	-	0.7	1	V

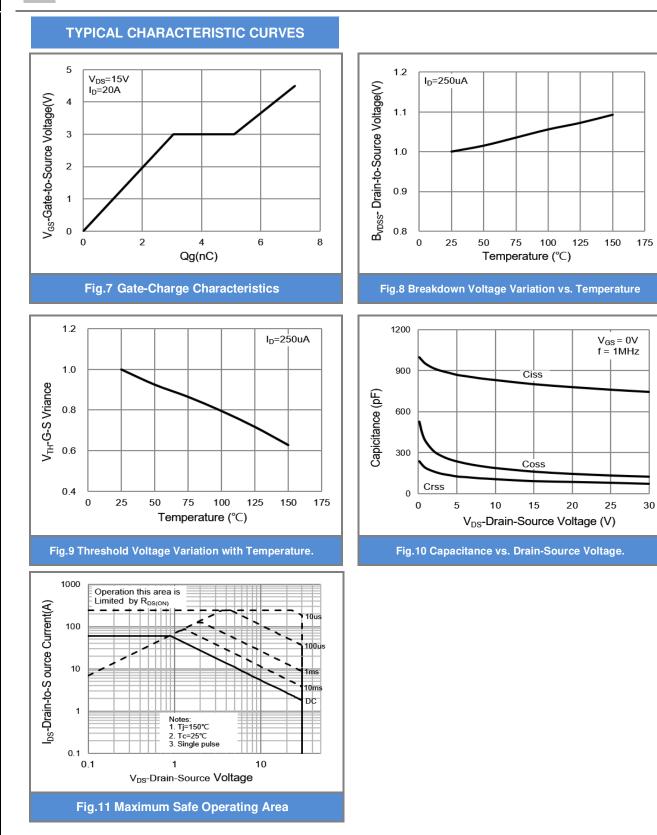
NOTES :

- 1. Pulse width
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial $T_J = 25$ °C.
- 4. The maximum current rating is package limited
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing





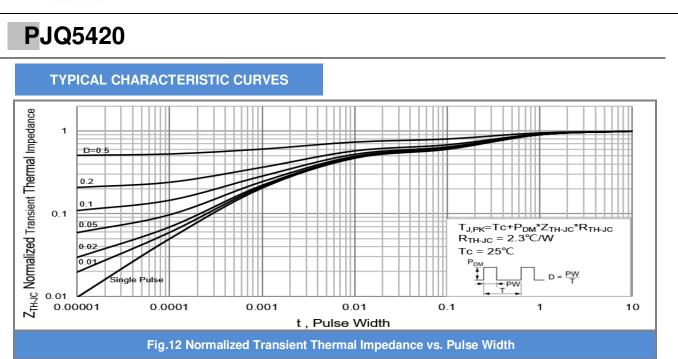












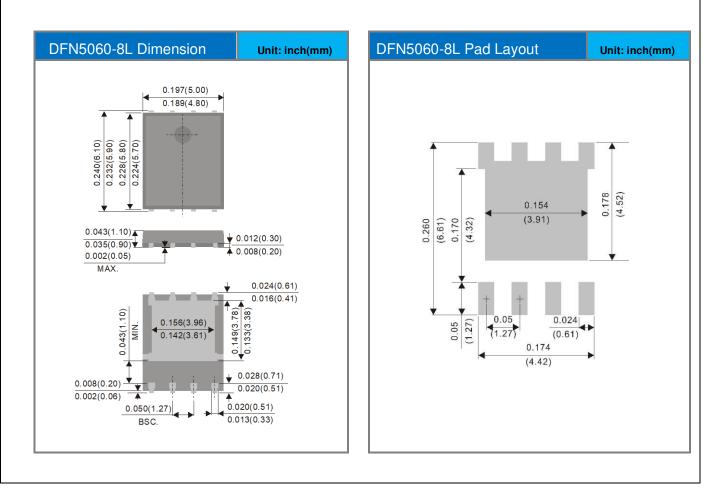




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5420_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5420	Halogen free

Packaging Information & Mounting Pad Layout







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